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01/18/2002

U.S. UTILITY Patent Application

PATENT NUMBER and ISSUE DATE					
APPL NUM 10050570	FILING DATE 01/18/2002	CLASS 117	SUBCLASS	GAU 1765	EXAMINER Song
**APPLICANTS: Yagi Kuniaki; Nagasawa Hiroyuki;					
**CONTINUING DATA VERIFIED: <i>None</i>					
** FOREIGN APPLICATIONS VERIFIED: JAPAN 11312/2001 01/19/2001 M)					
PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>		ATTORNEY DOCKET NO	
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiner's initials		<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no	ML		Q68148
TITLE : Single crystal SiCand method of producing the same as well as SiC semiconductor device and SiC composite material					
U.S. DEPT. OF COMM./PAT. & TM-PTO-435L(Rev. 12-94)					

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
Amount Due	Date Paid		Total Claims	Print Claim for O.G
ISSUE FEE		Primary Examiner	DRAWING	
			Sheets Drwg.	Figs.Drwg.
TERMINAL DISCLAIMER		Application Examiner		
PREPARED FOR ISSUE				
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